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AB-RTCMC-32.768kHz-IBO5-S3





3.7 x 2.5 x 0.9 mm

Moisture Sensitivity Level: MSL=1

FEATURES:

- Based on state-of-the-art RTC Technology by Micro Crystal AG
- Ultra-Low current consumption:
- XTAL Mode 60nA typ. @3.0V
- RC Mode 17nA typ. @3.0V
- RC Autocalibrated Mode 22nA typ. @3.0V
- RTC module with built-in crystal oscillating at 32.768 kHz
- Operating voltage: 1.5 3.6V
- Operating temperature range: -40 to +85°C
- Factory calibrated Time accuracy ±2.0ppm typ. @ 25°C
- Automatic Battery Switchover
- Trickle Charger, Power Management & Power Switch Function
- Programmable CLKOUT frequencies
- I²C Bus Interface (fast mode 400kHz)
- Time keeping mode down to 1.5 V
- Programmable Alarm, Timer and INT
- Up to 512 Bytes of general purpose RAM
- Small and compact package size: 3.7 x 2.5 x 0.9 mm. RoHS-compliant and 100% lead free

APPLICATIONS:

- Smart cards
- · Wireless sensors and tags
- Medical/Healthcare electronics
- Sports and fitness electronics
- Smart Utility meters
- · Data loggers
- Appliances
- Tracking systems
- Home security systems
- Industrial and Consumer electronics
- Communications equipment

> STANDARD SPECIFICATIONS:

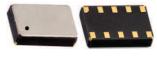
Absolute Maximum Ratings

Pai	rameters	Min.	Тур.	Max.	Units	Notes
Power Supply Vo	oltage (V _{DD})	-0.3		3.8	V	
Backup Supply v	voltage (V _{BACKUP})	-0.3		3.8	V	
Input Voltage	V _{DD} Power state	-0.3		$V_{DD} + 0.3$	V	
(V_I)	V _{BACKUP} Power State	-0.3		$V_{BACUUP} + 0.3$	V	
Output Voltage	V _{DD} Power state	-0.3		$V_{DD} + 0.3$	V	
(V_0)	V _{BACKUP} Power State	-0.3		$V_{BACUUP} + 0.3$	V	
Input Current (I _I)		-10		10	mA	
Output Current (I_{O})	-20		20	mA	
PSW Output Cor	ntinuous Current (I _{OPC})			50	mA	
PSW Output Pul	sed Current (I _{OPP})			150	mA	1 second pulse
ESD Voltage	CDM			±500	V	Charged Device Model
(V_{ESD})	HBM			±4000	V	Human Body Model
Latch-up Current	t (I _{LU})			100	mA	
Operating Tempe	erature Range (T _{OP})	-40		+85	°C	
Storage Tempera	ture (T _{STG})	-55		+125	°C	Stored as bare product
Lead Temperatur	re (T _{SLD})			+300	°C	Hand soldering for 10s
Reflow Soldering	g Temperature (T _{REF})			+260	°C	Reflow profile per JEDEC J-STD-020D



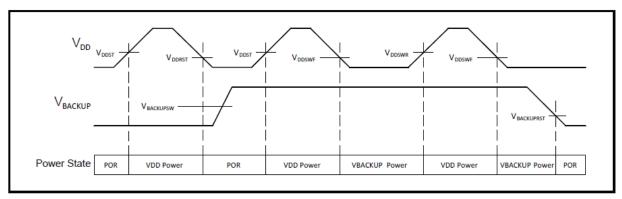






3.7 x 2.5 x 0.9 mm

Power Supply and Switchover Parameters



 $T_A = -40$ to +85°C, Typ. values at +25°C

Parameters	Type	Power State	Test Conditions	Min.	Typ.	Max.	Units
System Power Voltage (V_{DD})	Static	V _{DD} Power	Clocks operating and RAM and registers retained	1.5		3.6	V
V _{DD} I ² C Interface Voltage (V _{DDIO})	Static	V _{DD} Power	I ² C operation	1.5		3.6	V
V_{DD} Start-up Voltage $(V_{DDST})^{(1)}$	Rising	POR->V _{DD} Power		1.6			V
V_{DD} Reset Voltage (V_{DDRST})	Falling	V _{DD} Power -> POR	$V_{\scriptsize BACKUP}$ $<$ $V_{\scriptsize BACKUP,MIN}$ or no $V_{\scriptsize BACKUP}$		1.3	1.5	V
V_{DD} Rising Switch-over Threshold Voltage (V_{DDSWR})	Rising	V _{BACKUP} Power ->V _{DD} Power	$V_{\text{BACKUP}} \geq V_{\text{BACKRST}}$		1.6	1.7	V
V _{DD} Falling Switch-over Threshold Voltage (V _{DDSWF})	Falling	V _{DD} Power -> V _{BACKUP} Power	$V_{\text{BACKUP}}\!\geq\!V_{\text{BACKSW, MIN}}$	1.2	1.5		V
V_{DD} Switch-over Threshold Hysteresis $(V_{DDSWH})^{(2)}$	Hyst.	V _{DD} Power <-> V _{BACKUP} Power			70		mV
V_{DD} Falling Slew Rate to Switch to V_{BACKUP} State $(V_{DDFS})^{(4)}$	Falling	V _{DD} Power -> V _{BACKUP} Power	$V_{DD} < V_{DDSW,MAX}$	0.7	1.4		V
Backup Voltage (V _{BACKUP})	Static	V _{BACKUP} Power	Clocks operating and RAM and registers retained	1.4		3.6	V
Backup Switchover Voltage Range (V _{BACKSW}) ⁽⁵⁾	Static	V _{DD} Power -> V _{BACKUP} Power		1.6		3.6	V
Falling Backup POR Voltage (V _{BACKRST}) (7)	Falling	V _{BACKUP} Power -> POR	$V_{DD} < V_{DDSWF}$		1.1	1.4	V
V_{BACK} Margin above V_{DD} $(V_{BMRG})^{(3)}$	Static	V _{BACKUP} Power		200			mV
V _{BACK} Supply Series Resistance (R _{BACKESR}) ⁽⁶⁾	Static	V _{BACKUP} Power		1.0	1.5		kΩ



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3.7 x 2.5 x 0.9 mm

- (1) V_{DD} must be above V_{DDST} to exit the POR state, independent of the V_{BACKUP} voltage.
- (2) Difference between V_{DDSWR} and $V_{\text{DDSWF}}.$
- (3) V_{BACKUP} must be higher than V_{DD} by at least this voltage to insure the AB-RTCMC-32.768kHz-IBO5-S3 remains in the V_{BACKUP} Power state.
- (4) Maximum V_{DD} falling slew rate to guarantee correct switchover to V_{BACKUP} Power state. There is no V_{DD} falling slew rate requirement if switching to the V_{BACKUP} power source is not required.
- (5) V_{BACKUP} voltage to guarantee correct transition to V_{BACKUP} Power state when V_{DD} falls.
- (6) Total series resistance of the power source attached to the V_{BACKUP} pin. The optimal value is 1.5 k Ω , which may require an external resistor. V_{BACKUP} power source ESR (Equivalent Series Resistance) + external resistor value = 1.5 k Ω .
- (7) $V_{BACKRST}$ is also the static voltage required on V_{BACKUP} for register data retention.

Operating Parameters

 $T_A = -40$ to +85°C, Typ. values at +25°C

Parameters	Test Conditions	$ m V_{DD}$	Min.	Typ.	Max.	Units	
Positive-going Input		3.0V		1.5	2.0	V	
Threshold Voltage (V _{T+})		1.8V		1.1	1.25	V	
Negative-going Input		3.0V	0.8	0.9		V	
Threshold Voltage (V _{T-})		1.8V	0.5	0.6		V	
Input Leakage Current (I _{ILEAK})		3.0V		0.02	80	nA	
Input Capacitance (C _I)				3		pF	
		1.7V		1.7	5.8		
PSW Output Resistance to	DCW anablad	1.8V		1.6	5.4	0	
$V_{DD}(R_{DSON})$	PSW enabled	3.0V		1.1	3.8	Ω	
		3.6V		1.05	3.7		
Output Leakage Current (I _{OLEAK})		1.7V – 3.6V		0.02	80	nA	

Oscillator Parameters

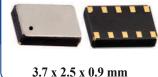
 $T_A = -40$ to +85°C unless otherwise indicated. $V_{DD} = 1.7$ to 3.6V, Typ. values at +25°C and 3.0V

Parameters	Test Conditions	Min.	Тур.	Max.	Units	
Crystal Frequency (F _{XT})			32.768		kHz	
XT Oscillator Failure Detection Frequency (F _{OF})			8		kHz	
Calibrated RC Oscillator Frequency (F _{RCC}) (1)	Factory calibrated at $+25$ °C, $V_{DD} = 2.8V$		64		Hz	
Uncalibrated RC Oscillator Frequency (F _{RCU})	Calibration disabled (OFFSETR=0) – 128Hz level	89	122	200	Hz	
Uncalibrated RC Oscillator	Calibration disabled (OFFSETR=0) – 128Hz level		2000			
Cycle-to-Cycle Jitter, Median (J _{RCCC})	Calibration disabled (OFFSETR=0) – 1Hz level		500		ppm	
	128Hz level at +25℃	-1		1		
RC Oscillator Cycle-to-Cycle Jitter, MIN, MAX (J _{RCCC})	128Hz level -10 to +70°C	-3.5		3.5	%	
JILLOI, IVIIIN, IVIAA (JRCCC)	128Hz level -40 to +85°C	-10		10		
XT Mode Digital Calibration Accuracy $(A_{XT})^{(1)}$	Calibrated at an initial temperature and voltage. Factory calibrated at $+25$ °C, $V_{DD} = 3.0$ V	-2		+2	ppm	









(Continued)

 $T_A = -40$ to +85°C unless otherwise indicated. $V_{DD} = 1.7$ to 3.6V, Typ. values at +25°C and 3.0V

Parameters	Test Conditions	Min.	Тур.	Max.	Units	
	24 hour run time		35			
Autocalibration Mode Timing	1 week run time		20		10.10.100	
Accuracy, 512 second period, T_A = -10 to +60°C $(A_{AC})^{(1)}$	1 month run time		10		ppm	
-10.00 ± 000 C (A_{AC})	1 year run time		3		1	
Autocalibration Mode Operating Temperature $(T_{AC})^{(2)}$		-10		+60	°C	

- (1) Timing accuracy is specified at 25°C after digital calibration of the internal RC oscillator and digital calibration of the 32.768 kHz crystal. The 32.768 kHz tuning fork crystal has a negative temperature coefficient with a parabolic frequency deviation, which can result in a change of up to 150 ppm across the entire operating temperature range of -40°C to 85°C in XT mode. Autocalibration mode timing accuracy is specified relative to XT mode timing accuracy from -10°C to 60°C.
- (2) Outside of this temperature range, the RC oscillator frequency change due to temperature may be outside of the allowable RC digital calibration range (+/-12%) for autocalibration mode. When this happens, an autocalibration failure will occur and the ACF interrupt flag is set. The AB-RTCMC-32.768kHz-IBO5-S3 should be switched to use the XT oscillator as its clock source when this occurs. Please see the AUTOCALIBRATION FAILURE section in the application manual for more details.

XT Frequency Characteristics

 $T_A = -40$ to +85°C unless otherwise indicated. $V_{DD} = 1.7$ to 3.6V, Typ. values at +25°C and 3.0V, $f_{OSC} = 32.768$ kHz

Parameters	Test Conditions	Min.	Тур.	Max.	Units
Frequency Accuracy (ΔF/F)	$T_A = +25$ °C; Calibration disabled (OFFSETX=0)		±100 ⁽¹⁾		ppm
Frequency vs. Temperature Characteristics ($\Delta F/F_0$)	$T_{OPR} = -40 \text{ to } +85^{\circ}\text{C}$	$-0.035^{\text{ppm}}/_{\text{C}}^2 * (T_{\text{OPR}}-T_0)^2 \pm 10\%$			ppm
Turnover Temperature (T ₀)		+20	+25	+30	°C
Aging First Year	$T_A = +25$ °C			±3	ppm
Oscillator Start-up Voltage	$T_A = -40 \text{ to } +85^{\circ}\text{C}$	1.6			V
Oscillator Start-up Time	$V_{DD} = 1.7V - 3.6V$		1.0		S
CLKOUT Duty Cycle	$F_{\text{CLKOUT}} = 32.768 \text{kHz};$ $T_{\text{A}} = +25^{\circ}\text{C}$	50	60	70	%

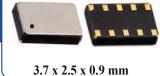
(1) The XT mode digital calibration accuracy is +/-2 ppm, see OSCILLATOR PARAMETERS.



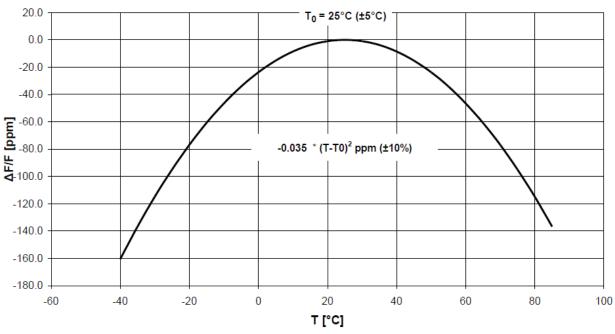


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XT Frequency vs. Temperature Characteristics



V_{DD} Supply Current

 $T_A = -40$ to +85°C. $V_{BACKUP} = 0$ to 3.6V, Typ. values at +25°C, V_{DD} power state

Parameters	Test Conditions	V_{DD}	Min.	Тур.	Max.	Units	
V _{DD} Supply Current during I2C	400kHz bus speed, 2.2k pull-	3.0V		6	10	μА	
burst Read/Write (I _{VDD:12C})	up resistors on SCL/SDA (1)	1.8V		1.5	3	μΑ	
V _{DD} Supply Current in XT	Time keeping mode with XT	3.0V		60	330	nA	
Oscillator Mode (I _{VDD:XT})	oscillator running (2)	1.8V		27	290	ПА	
V _{DD} Supply Current in RC	Time keeping mode with only the RC oscillator running (XT	3.0V		17	220	nA	
Oscillator Mode ($I_{VDD:RC}$) the RC oscillator running (X1 oscillator is off) (2)		1.8V		14	170	ПА	
Average V _{DD} Supply Current in Autocalibrated RC Oscillator	Time keeping mode with only the RC oscillator running and	3.0V		22	235	nA	
Mode (I _{VDD:ACAL})	Autocalibration enabled. ACP=512 seconds (2)	1.8V		18	190	ША	
Additional V _{DD} Supply Current	Time keeping mode with XT oscillator running, 32.768kHz	3.0V		0.71			
with CLK/INT at 32.768kHz (I _{VDD:CK32})	square wave on CLK/INT (3)	1.8V		0.34		μA	
Additional V _{DD} Supply Current with CLK/INT at 64Hz	All time keeping mode, 64Hz	3.0V		0.6		nA	
With CLK/INT at 64HZ (I _{VDD:CK64})	square wave on CLK/ INT (3)	1.8V		0.3		11/4	



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- (1) Excluding external peripherals and pull-up resistor current. All other inputs (besides SDA and SCL) are at 0V or V_{DD} . Test conditions: Continuous burst read/write, 55h data pattern, 25 μ s between each data byte, 20 pF load on each bus pin.
- (2) All inputs and outputs are at 0V or V_{DD} .
- (3) All inputs and outputs except CLK / INT are at 0V or V_{DD}. 15 pF load on CLK / INT, pull-up resistor current not included.

VBACKUP Supply Current

 T_A = -40 to +85°C. Typ. values at +25°C, Max. values at +85°C. V_{BACKUP} power state

Parameters	Test Conditions	$V_{ m DD}$	V _{BACK}	Min.	Тур.	Max.	Units
V _{BACKUP} Supply Current in XT Oscillator Mode	Time keeping mode with XT	A.	3.0V		63	330	12 A
$(I_{VBACK:XT})$	oscillator running (1)	<v<sub>DDSWF</v<sub>	1.8V		60	290	nA
V _{BACKUP} Supply Current in RC Oscillator Mode	Time keeping mode with only	A.	3.0V		19	220	12 A
(I _{VBACK:RC})	oscillator is off) (1)	oscillator running (XT <v<sub>DDSWF scillator is off) (1)</v<sub>			16	170	nA
Average V _{BACKUP} Supply Current in Autocalibrated	Time keeping mode with only the RC oscillator running and	W	3.0V		25	235	nA
RC Oscillator Mode (I _{VBACK:ACAL})	Autocalibration enabled. ACP=512 seconds (1)	<v<sub>DDSWF</v<sub>	1.8V		21	190	IIA
V _{BACKUP} Supply Current in	V	1726	3.0V	-5	0.6	20	A
V_{DD} powered mode $(I_{VBACK:VDD})$	V _{DD} powered mode ⁽¹⁾	1.7-3.6V	1.8V	-10	0.5	16	nA

⁽¹⁾ Test conditions: All inputs and outputs are at 0V or V_{DD} .

BREF Electrical Characteristics

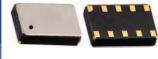
 $T_A = -20 \text{ to } +70^{\circ}\text{C}$. Typ. values at $+25^{\circ}_{DD}$, V = 1.7 to 3.6V.

Parameters	BREF	Min.	Тур.	Max.	Units	
V_{BACKUP} Falling Threshold (V_{BRF})	0111	2.3	2.5	3.3		
	1011	1.9	2.1	2.8	V	
	1101	1.6	1.8	2.5	·	
	1111		1.4			
	0111	2.6	3.0	3.4		
V _{BACKUP} Rising Threshold	1011	2.1	2.5	2.9	v	
(V_{BRR})	1101	1.9	2.2	2.7	v	
	1111		1.6			









3.7 x 2.5 x 0.9 mm

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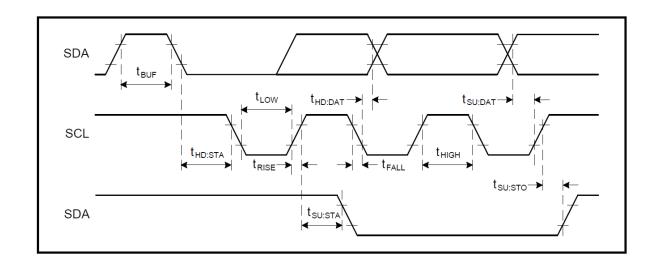
 $T_A = -20 \text{ to } +70 \text{ °C}$. Typ. values at +25 °C, $V_{DD} = 1.7 \text{ to } 3.6 \text{ V}$.

Parameters	Parameters BREF		Тур.	Max.	Units
V_{BACKUP} Threshold Hysteresis (V_{BRH})	0111		0.5		
	1011		0.4		V
	1101		0.4		V
	1111		0.2		
BREF/BPOL Change to BBOD Valid (t _{BREF})	All valid BREF values		1000		ms
V _{BACKUP} Analog Comparator Recommended Operating Temperature Range (T _{BR})	All valid BREF Values	-20		+70	°C

I²C AC Electrical Characteristics

 $T_A = -40$ to +85°C. Typ. values at +25°C

Parameters	$V_{ m DD}$	Min.	Тур.	Max.	Units
SCL Input Clock Frequency (f _{SCL})	1.7 – 3.6V	10		400	kHz
Low Period of SCL Clock (t _{LOW})	1.7 – 3.6V	1.3			μs
High Period of SCL Clock (t _{HIGH})	1.7 – 3.6V	600			ns
Rise Time of SDA and SCL (t _{RISE})	1.7 – 3.6V			300	ns
Fall Time of SDA and SCL (t _{FALL})	1.7 – 3.6V			300	ns
START Condition Hold Time (t _{HD:STA})	1.7 – 3.6V	600			ns
START Condition Setup Time (t _{SU:STA})	1.7 – 3.6V	600			ns
SDA Setup Time (t _{SU:DAT})	1.7 – 3.6V	100			ns
SDA Hold Time (t _{HD:DAT})	1.7 – 3.6V	0			ns
STOP Condition Setup Time (t _{SU:STO})	1.7 – 3.6V	600			ns
Bus Free Time before a New Transmission (t _{BUF})	1.7 – 3.6V	1.3			μs



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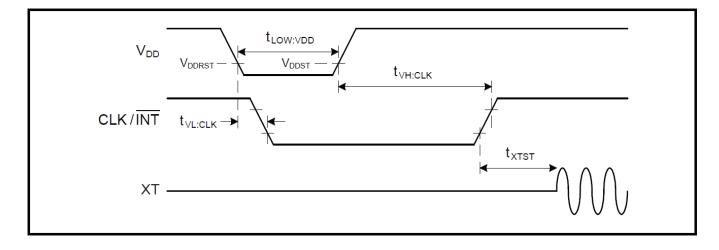




Power-on AC Electrical Characteristics

 $T_A = -40 \text{ to } +85^{\circ}\text{C. } V_{BACKUP} < 1.2\text{V}$

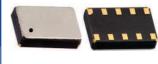
Parameters	$V_{ m DD}$	T _A	Min.	Typ.	Max.	Units
		+85°C		0.1		
Low Period of V _{DD} to Ensure a Valid POR	1.7 – 3.6V	+25°C		0.1		1
$(t_{LOW:VDD})$		-20°C		1.5		S
		-40°C		10]
		+85°C		0.1		
V V V V V V V V V V V V V V V V V V V	17 260	+25°C		0.1		s
V_{DD} Low to CLK/INT Low ($t_{VL:CLK}$)	1.7 – 3.6V	-20°C		1.5		
		-40°C		10		
		+85°C		0.4		s
	17 200	+25°C		0.5		
V_{DD} High to CLK/INT High ($t_{VH:CLK}$)	1.7 - 3.6V	-20°C		3		
		-40°C		20		
		+85°C		0.4		S
	1.7 – 3.6V	+25°C		0.4		
CLK/INT High to XT Oscillator Start (t _{XTST})		-20°C		0.5		
		-40°C		1.5		









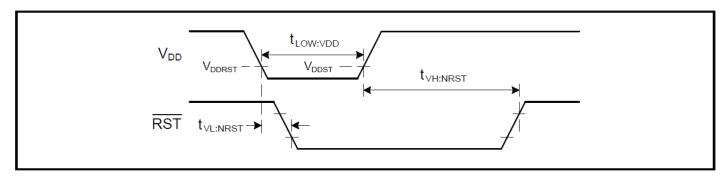


3.7 x 2.5 x 0.9 mm

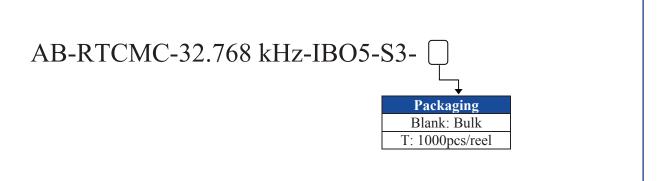
RST AC Electrical Characteristics

 $T_A = -40 \text{ to } +85^{\circ}\text{C. } V_{BACKUP} < 1.2\text{V}$

Parameters	V_{DD}	$T_{\mathbf{A}}$	Min.	Тур.	Max.	Units
Low Period of V_{DD} to Ensure a Valid POR $(t_{LOW:VDD})$	1.7 – 3.6V	+85°C		0.1		s
		+25°C		0.1		
		-20°C		1.5		
		-40°C		10		
V_{DD} Low to \overline{RST} Low $(t_{VL:NRST})$	1.7 – 3.6V	+85°C		0.1		S
		+25°C		0.1		
		-20°C		1.5		
		-40°C		10		
V_{DD} High to \overline{RST} High $(t_{VH:NRST})$	1.7 – 3.6V	+85°C		0.5		S
		+25°C		0.5		
		-20°C		3.5		
		-40°C		25		



▶ PART IDENTIFICATION:

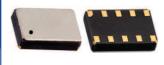






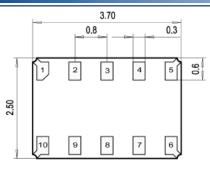
AB-RTCMC-32.768kHz-IBO5-S3

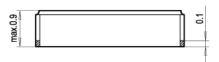




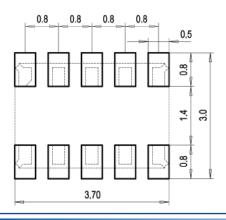
3.7 x 2.5 x 0.9 mm

OUTLINE DIMENSION:





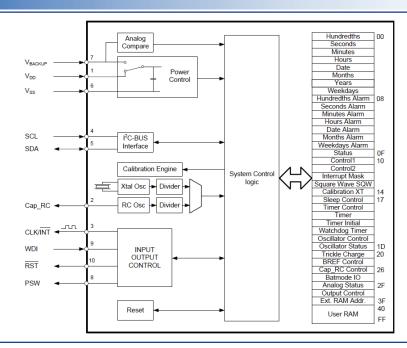
Recommended Land Pattern



Pin No.	Pin Name	Function	
1	V_{DD}	Power Supply Voltage	
2	Cap_RC	Capacitor RC-Oscillator	
3	CLK/ INT	Clock Output/Interrupt	
4	SCL	Serial Clock Input	
5	SDA	Serial Data	
6	V_{SS}	Ground	
7	V_{BACKUP}	Backup Supply Voltage	
8	PSW	Power Switch Output	
9	WDI	Watchdog Input	
10	RST	Reset Output	

Dimensions: mm

BLOCK DIAGRAM:



ABRACON IS ISO 9001 : 2008 CERTIFIED



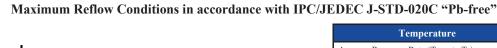
AB-RTCMC-32.768kHz-IBO5-S3

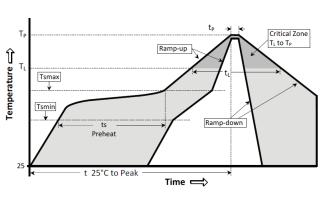




3.7 x 2.5 x 0.9 mm

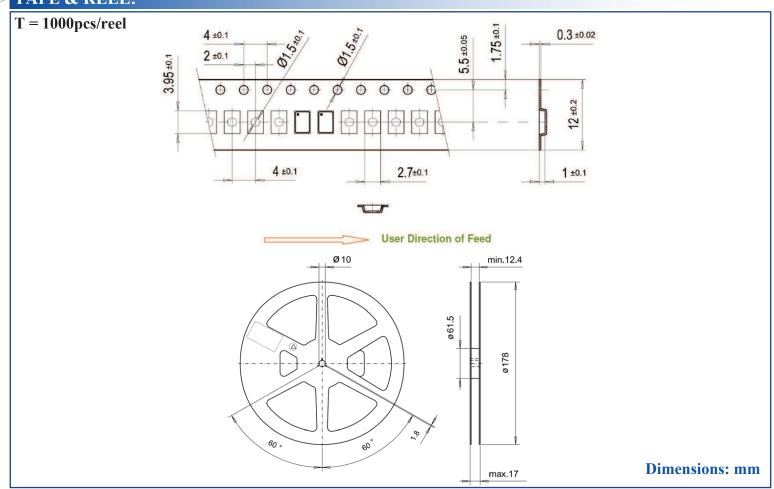
REFLOW PROFILE:





Temperature	Conditions	Units
Average Ramp-up Rate (T _{Smax} to T _P)	3°C/second max	°C/s
Ramp Down Rate (T _{cool})	6°C/second max	°C/s
Time 25°C to Peak Temperature (T to-peak)	8 minutes max	m
Preheat		
Temperature Min (T _{Smin})	150	℃
Temperature Max (T _{Smax})	200	°C
Time Ts _{min} to Ts _{max} (ts)	60 ~ 180	sec
Time Above Liquidus		
Temperature Liquidus (T _L)	217	℃
Time above Liquidus (t _L)	60~150	sec
Peak Temperature		•
Peak Temperature (T _P)	260	°C
Time within 5°C of Peak Temperature (t _P)	20 ~ 40	sec

► TAPE & REEL:



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